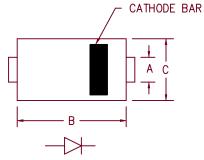
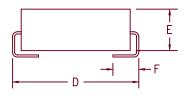
1 Amp Ultra Low Forward Voltage Schottky Diode LSM115J



Dim. Inches			Millimeter		
	Minimum	Maximum	Minimum	Maximum	Notes
A	.073	.087	1.85	2.21	
В	.160	.180	4.06	4.57	
С	.130	.155	3.30	3.94	
D	.205	.220	5.21	5.59	
Е	.075	.130	1.91	3.30	
F	.030	.060	.760	1.52	



DO-214BA Package

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Microsemi Catalog Number	Working Peak Reverse Voltage	Repetitive Peak Reverse Voltage	 Schottky Barrier Rectifier Guard Ring For Reverse Protection Low Power Loss, High Efficiency
LSM115J	15V	15V	 100°C Junction Temperature VRRM 15V High Surge Capability Ultra Low Forward Voltage Schottky OR'ing diode

Electrical Characteristics					
Average forward current Maximum surge current Maximum peak forward voltage Maximum peak reverse current Maximum peak reverse current Maximum peak reverse current Typical junction capacitance	^I F(AV) 1 Amps ^I FSM 50 Amps ^V FM 0.29 Volts ^I RM 500 mA ^I RM 200 mA ^I RM 100 mA ^I RM 10 mA CJ 120pF	${}^{T}L = 65^{\circ}$ C, Square wave, ${}^{R}\Theta JL = 15^{\circ}$ C/V 8.3ms, half sine, ${}^{T}J = 100^{\circ}$ C ${}^{I}FM = 1.0A: {}^{T}J = 25^{\circ}$ C * ${}^{V}RRM = 15V, {}^{T}J = 100^{\circ}$ C ${}^{V}R = 5V, {}^{T}J = 100^{\circ}$ C ${}^{V}R = 3.3V, {}^{T}J = 100^{\circ}$ C ${}^{V}RRM = 15V, {}^{T}J = 25^{\circ}$ C ${}^{T}J = 25^{\circ}$ C, ${}^{V}R = 5V$			

Thermal and Mechanical Characteristics

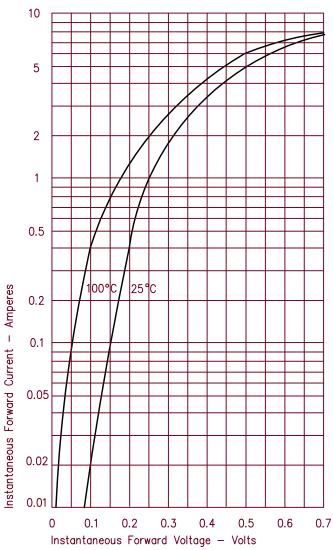
Storage temperature range Operating junction temp range Maximum thermal resistance Weight	TSTG TJ R _{θJL}	-55°C to 150°C -55°C to 100°C 15°C/W Junction to Lead .0047 ounces (.013 grams) typical
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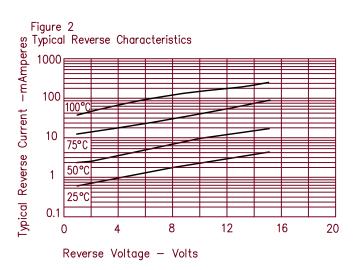


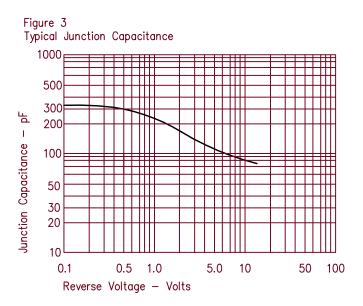
800 Hoyt Street Broomfield, CO. 80020 PH: (303) 469–2161 FAX: (303) 466–3775 www.microsemi.com 4-3-00 Rev. 2

LSM115J

Figure 1 Typical Forward Characteristics







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